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WR811X



Features

- Precision voltage monitor for 3V, 3.3V or 5V power supplies
- $\bullet \quad \text{Reset remains valid with V_{CC} as low as } \\ 1V$
- 140ms minimum reset pulse width available
- 3µA typical supply current
- Available in 5-pin SOT23-5Lpackage

Applications

- Computer
- Controller
- Intelligent Instruments
- Critical uP and uC Power Monitoring
- Portable/Battery-Powered Equipment

Description

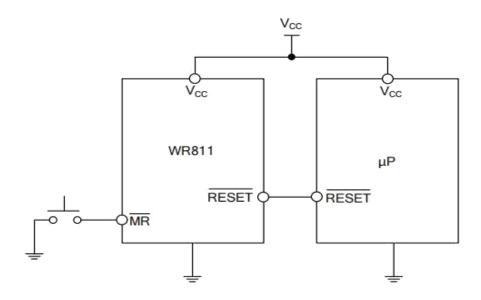
The WR811X is a low-power microprocessor (μP) supervisory circuit used to monitor power supplies in microprocessor and digital systems. Low supply current makes the WR811 ideal for use in portable equipment. The device comes in a 5-pin SOT23-5L package.

The WR811X provides excellent circuit reliability and low BOM cost by eliminating external components and adjustments when used with 5V-powered or 3V-powered circuits. The WR811X also provides a debounced manual reset input.

The function of this device is to assert a reset if either the power supply drops below a designed

reset threshold level or MR is forced low. The reset comparator is designed to ignore fast transients on V_{CC} . Reset thresholds are available for operation with a variety of supply voltages.

Typical Application Circuit

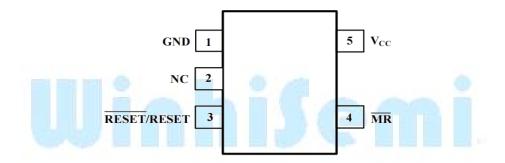


WR811X

Ordering and Marking Information

Part Number	Marking Code	package
WR811	WR811X YWWXX	SOT23-5L
	WR811X= Device code	
	YWWXX=Special Code	

Pin Configuration



Pin Description

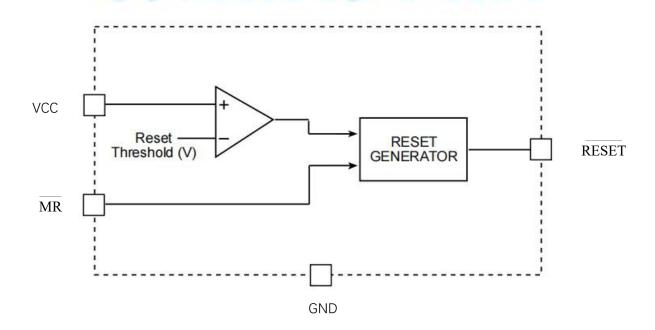
Pin No.	Name	Function
1	GND	IC Ground Pin.
2	NC	
3	RESET	\overline{RESET} goes low if V_{CC} falls below the reset threshold and remains asserted for one reset timeout period after V_{CC} exceeds the reset threshold.
4	MR	Manual Reset Input. A logic low on MR forces a reset timeout period after MR goes high. This input can be shorted to ground via a switch or driven from CMOS or TTL logic. Float if unused.
5	VCC	Power Supply

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Absolute Maximum Values

Parameter	Symbol	Value	Unit
Terminal Voltage(V _{CC})	V _{CC}	-0.3 to 6.0V	V
Input Current(V_{CC} , \overline{MR})	V _{CC} , MR	20	mA
Output Current(RESET)	RESET	20	mA
ESD Rating		3	KV
Lead Temperature(soldering,10sec)		300	$^{\circ}\mathrm{C}$
Junction Temperature		150	°C
Storage Temperature		-65 to 160	°C
Junction Temperature		150	°C
Storage Temperature		-65 to 150	°C
SOT23-5L Package Thermal Resistance	$R_{ heta JA}$	250	°C/W
SOT23-5L Package Thermal Resistance	$R_{ heta JC}$	115	°C/W

Functional Diagram



Electrical Characteristics

WR811-T(3.08) (TA = +25°C unless otherwise stated, VCC = 5.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Operation Voltage Range	V _{CC}	1		5.5	V	T_A =-40°C to 85°C
Supply Current	I_{CC}		3	8	μΑ	V _{CC} =3.3V, no load
Reset Voltage Threshold	V_{TH}	3	3.08	3.15	V	
Reset Timeout Period	t _{RST}	140		560	ms	
	V _{OH}	$0.8 \times V_{CC}$			V	I _{SOURECE} =500μA
	V _{OL}			0.3	V	V _{CC} =V _{TH} min, I _{SINK} =1.2mA
RESET Output Voltage				0.3	V	V _{CC} >1V,I _{SINK} =50μA, T _A =-40°C to 85°C
MR Minimum Pulse Width		10			μs	
MR to Reset Delay			0.5		μs	
	V_{IH}	$0.7 \times V_{CC}$			V	
MR Input Threshold	V_{IL}			$0.25 \times V_{CC}$	V	
MR Pull-Up resistance	H 0	10	20	30	kΩ	•
MR Glitch Immunity			100	4	ns	

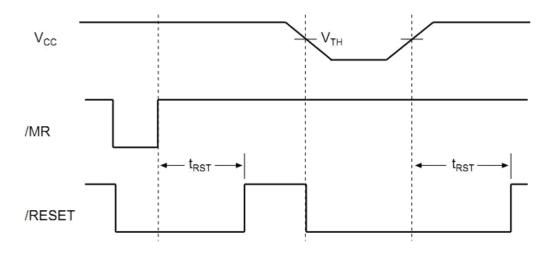
WR811-L(4.63) ($T_A = +25$ °C unless otherwise stated, VCC = 5.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Operation Voltage Range	V_{CC}	1		5.5	V	T _A =-40°C to 85°C
Supply Current	I_{CC}		3	8	μΑ	V _{CC} =3.3V, no load
Reset Voltage Threshold	V_{TH}	4.5	4.63	4.8	V	
Reset Timeout Period	t_{RST}	140		560	ms	
	V _{OH}	$0.8 \times V_{CC}$			V	I _{SOURECE} =500μA
	T/			0.3	V	V _{CC} =V _{TH} min, I _{SINK} =1.2mA
RESET Output Voltage	V _{OL}			0.3	V	V_{CC} >1V, I_{SINK} =50 μ A, T_{A} =-40°C to 85°C
MR Minimum Pulse		10			μs	
MR to Reset Delay			0.5		μs	
MR Input Threshold	$V_{ m IH}$	$0.7 \times V_{CC}$			V	
	V_{IL}			$0.25 \times V_{CC}$	V	
MR Pull-Up resistance		10	20	30	kΩ	
MR Glitch Immunity			100		ns	

WR811-R(2.63) (TA = +25°C unless otherwise stated, VCC = 5.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Operation Voltage Range	V_{CC}	1		5.5	V	T_A =-40°C to 85°C
Supply Current	I_{CC}		3	8	μΑ	V _{CC} =3.3V, no load
Reset Voltage Threshold	V_{TH}	2.58	2.63	2.68	V	
Reset Timeout Period	t_{RST}	140		560	ms	
	V _{OH}	$0.8 \times V_{CC}$			V	I _{SOURECE} =500μA
	V _{OL}			0.3	V	V _{CC} =V _{TH} min, I _{SINK} =1.2mA
RESET Output Voltage				0.3	V	V _{CC} >1V,I _{SINK} =50μA, T _A =-40°C to 85°C
MR Minimum Pulse Width		10			μs	
MR to Reset Delay			0.5		μs	
	$V_{ m IH}$	$0.7 \times V_{CC}$			V	
MR Input Threshold	V _{IL}			0.25×V _{CC}	V	
MR Pull-Up resistance		10	20	30	kΩ	
MR Glitch Immunity	<u> </u>		100		ns	

Timing Diagram



Reset Timing Diagram

Sep. 2023, Rev 1.0

Application Information

Microprocessor Reset

The RESET pin is asserted whenever V_{CC} falls below the reset threshold voltage. The RESET pin remains asserted for a period of 140ms after V_{CC} has risen above the reset threshold voltage. The reset and powers up in a known condition after a power failure. RESET will remain valid with V_{CC} as low as 1V.

VCC Transients

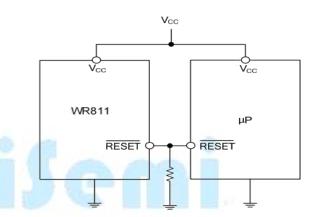
The WR811 is relatively immune to negative-going VCC glitches below the reset threshold. Typically, a negative-going transient 125 mV below the reset threshold with a duration of $20 \mu \text{s}$ or less will not cause a reset.

Interfacing to Bidirectional Reset Pins

The WR811 can interface with μPs with bidirectional reset pins by connecting a $4.7k\Omega$ resistor in series with the WR811 output and the μP reset pin.

RESET Valid at Low Voltage

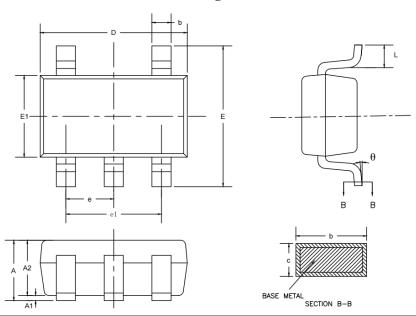
A resistor can be added from the RESET pin to ground to ensure the RESET output remains low with VCC down to 0V. A $100k\Omega$ resistor connected from the RESET to ground is recommended. The size of the resistor should be large enough not to load the output excessively and small enough to pull-down any stray leakage currents.



WR811X

Mechanical Dimensions

SOT23-5L Package Information



COMMON DIMENSIONS						
UNITS OF MEASURE=MILLIMETER						
SYMBOL	MIN	MAX				
Α	0.9	1.45				
A1	0	0.15				
A2	0.9	1.3				
b	0.28	0.5				
С	0.1	0.23				
D	2.82	3.05				
E	2.6	3				
E1	1.5	1.75				
е	0.9	0.95BSC				

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Reset Microchip with Low Voltage Detec	WR811X	
e1	1.8	2
L	0.3	0.6
θ	0°	8°



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